

### FEATURES

- Single-supply operation: 4.5 V to 18 V**
- Upper/lower buffers swing to V<sub>S</sub>/GND**
- Gamma continuous output current: >10 mA**
- V<sub>COM</sub> peak output current: 250 mA**
- Offset voltage: 12 mV**
- Slew rate: 8 V/μs**
- Unity gain stable with large capacitive loads**
- Supply current: 700 μA per amplifier**
- Compact 28-lead TSSOP**
- Pb-free package**
- Drop-in replacement for BUF11702**

### APPLICATIONS

- TFT LCD monitor panels**
- TFT LCD notebook panels**

### GENERAL DESCRIPTION

The ADD8710 is a low cost, 10-channel gamma buffer with a V<sub>COM</sub> driver that operates from a single supply. The part is designed for high resolution TFT LCD panels and is built on an advanced, high voltage CBCMOS process.

The gamma buffers have a high slew rate, minimum 10 mA output current, and a high capacitive load drive capability. The V<sub>COM</sub> buffer is capable of delivering 250 mA of peak current and can also drive large capacitive loads. The ADD8710 offers a wide supply range and offset voltages below 12 mV.

The ADD8710 is specified over the -40°C to +85°C temperature range and is available in a Pb-free, 28-lead TSSOP package.

### PIN CONFIGURATION

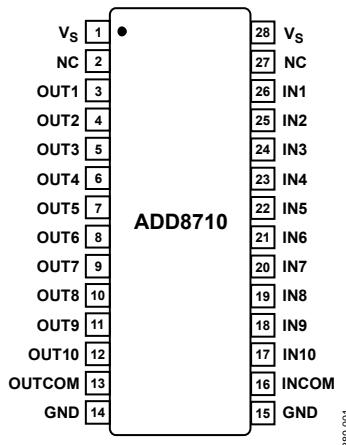


Figure 1. 28-Lead TSSOP (RU Suffix)

04889-001

### FUNCTIONAL BLOCK DIAGRAM

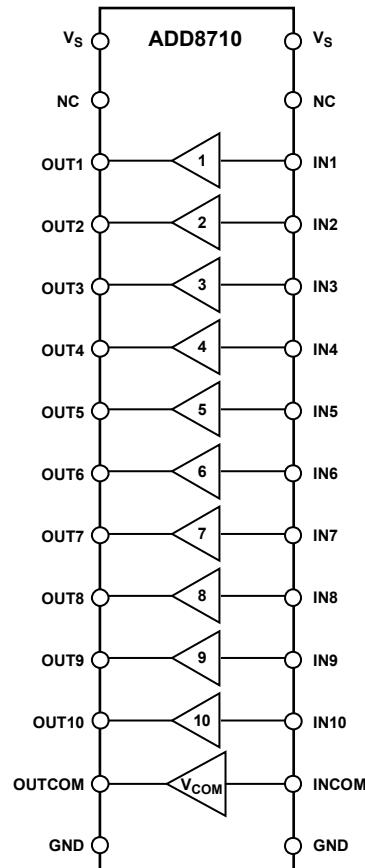


Figure 2.

04889-002

Rev. B

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## REVISION HISTORY

### 6/07—Rev. A to Rev. B

Changes to Figure 18..... 7

### 3/05—Rev. 0 to Rev. A

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### 6/04—Revision 0: Initial Version

## SPECIFICATIONS

$V_S = 16 \text{ V}$ ,  $V_{CM} = V_S/2$ ,  $T_A @ 25^\circ\text{C}$ , unless otherwise noted.

Table 1.

Parameter	Symbol	Condition	Min	Typ	Max	Unit
INPUT CHARACTERISTICS						
Offset Voltage	$V_{OS}$		4	12		mV
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$	$-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$	5			$\mu\text{V}/^\circ\text{C}$
Input Bias Current	$I_B$	$-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$	0.5	1.1	1.5	$\mu\text{A}$
Input Impedance	$Z_{IN}$		400			k $\Omega$
Input Capacitance	$C_{IN}$		1			pF
BUFFER CHARACTERISTICS						
Common-Mode Input Range	$V_{CMM}$		1.25			V
Buffer 1 to Buffer 5			0			$V_S - 1.25$
Buffer 6 to Buffer 10						V
Output Voltage High (V1)	$V_{OH}$	$V_S = 16 \text{ V}, V_{IN} = 16 \text{ V}, I_L = 10 \text{ mA}$ $V_S = 10 \text{ V}, V_{IN} = 9.8 \text{ V}, I_L = 10 \text{ mA}$ $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$	15.82	15.9		V
Output Voltage High (V2 to V5)	$V_{OH}$	$V_S = 10 \text{ V}, V_{IN} = 8.5 \text{ V}, I_L = 10 \text{ mA}$ $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$	9.75	9.8		V
Output Voltage High (V6 to V10)	$V_{OH}$	$V_S = 10 \text{ V}, V_{IN} = 8 \text{ V}, I_L = 10 \text{ mA}$ $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$	8.45	8.5		V
Output Voltage Low (V1 to V5)	$V_{OL}$	$V_S = 10 \text{ V}, V_{IN} = 2 \text{ V}, I_L = 10 \text{ mA}$ $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$	8.4	2	2.05	V
Output Voltage Low (V6 to V9)	$V_{OL}$	$V_S = 10 \text{ V}, V_{IN} = 1.5 \text{ V}, I_L = 10 \text{ mA}$ $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$	7.95	7.9	1.55	V
Output Voltage Low (V10)	$V_{OL}$	$V_S = 16 \text{ V}, V_{IN} = 0 \text{ V}, I_L = 10 \text{ mA}$ $V_S = 10 \text{ V}, V_{IN} = 0.2 \text{ V}, I_L = 10 \text{ mA}$ $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$	7.9	0.1	0.175	V
Continuous Output Current	$I_{OUT}$			0.2	0.25	V
Peak Output Current	$I_{PK}$	$V_S = 16 \text{ V}$		0.3		V
				10		mA
				100		mA
$V_{COM}$ CHARACTERISTICS						
Common-Mode Input Range	$V_{CMM}$		0			V
Output Voltage High	$V_{OH}$	$V_S = 10 \text{ V}, V_{IN} = 8 \text{ V}, I_L = 30 \text{ mA}$ $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$	7.95	8		V
Output Voltage Low	$V_{OL}$	$V_S = 10 \text{ V}, V_{IN} = 2 \text{ V}, I_L = 30 \text{ mA}$ $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$	7.9	2	2.05	V
Continuous Output Current	$I_{OUT}$			2.10		V
Peak Output Current	$I_{PK}$	$V_S = 16 \text{ V}$		35		mA
				250		mA
SUPPLY CHARACTERISTICS						
Supply Voltage	$V_S$		4.5			V
Power Supply Rejection Ratio	PSRR	$V_S = 4.5 \text{ V to } 16.5 \text{ V}, -40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$	70	90		dB
Total Supply Current	$I_{SY}$	$V_O = V_S/2$ , no load $-40^\circ\text{C} \leq T_A \leq +85^\circ\text{C}$		7.7	10	mA
					11.5	mA
DYNAMIC PERFORMANCE						
Slew Rate	SR	$R_L = 2 \text{ k}\Omega, C_L = 200 \text{ pF}$	4	8		V/ $\mu$ s
Bandwidth	BW	$-3 \text{ dB}, R_L = 10 \text{ k}\Omega, C_L = 200 \text{ pF}$		5		MHz
Settling Time to 0.1% (Buffers)	$t_s$	1 V step, $R_L = 10 \text{ k}\Omega, C_L = 200 \text{ pF}$		1.1		$\mu$ s
Settling Time to 0.1% ( $V_{COM}$ )	$t_s$	1 V step, $R_L = 10 \text{ k}\Omega, C_L = 200 \text{ pF}$		0.7		$\mu$ s
Phase Margin	$\Phi_0$	$R_L = 10 \text{ k}\Omega, C_L = 200 \text{ pF}$		45		Degrees
Channel Separation				75		dB

## ABSOLUTE MAXIMUM RATINGS

Table 2.

Parameter	Rating
Supply Voltage ( $V_S$ )	18.5 V
Input Voltage	-0.5 V to $V_S + 0.5$ V
Storage Temperature Range	-65°C to +150°C
Operating Temperature Range	-40°C to +85°C
Junction Temperature Range	-65°C to +150°C
Lead Temperature	300°C
ESD Tolerance (HBM)	±2500 V
ESD Tolerance (MM)	±200 V

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## THERMAL RESISTANCE

$\theta_{JA}$  is specified for the worst-case conditions, that is, a device soldered in a circuit board for surface-mount packages.

Table 3. Thermal Resistance

Package Type	$\theta_{JA}$	Unit
28-Lead TSSOP (RU)	67.7	°C/W

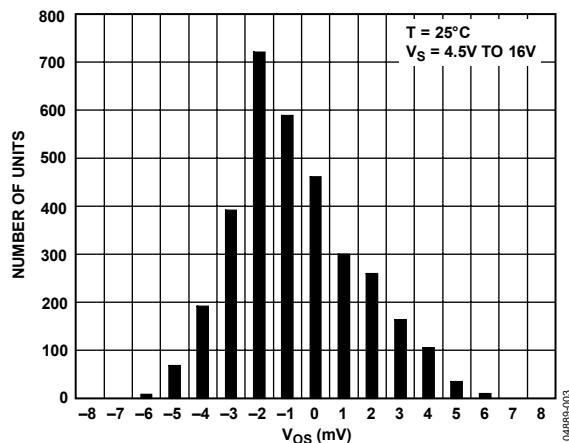
## ESD CAUTION



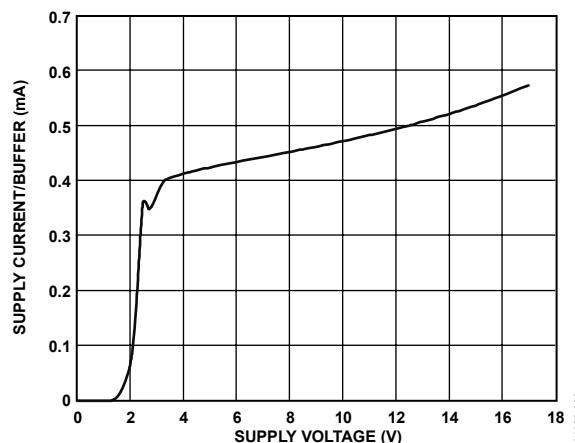
### ESD (electrostatic discharge) sensitive device.

Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

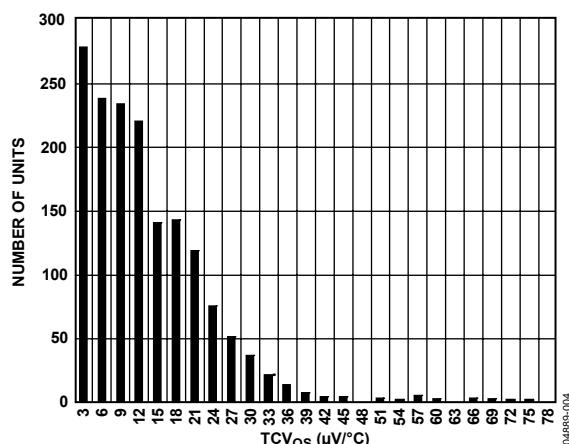
## **TYPICAL PERFORMANCE CHARACTERISTICS**



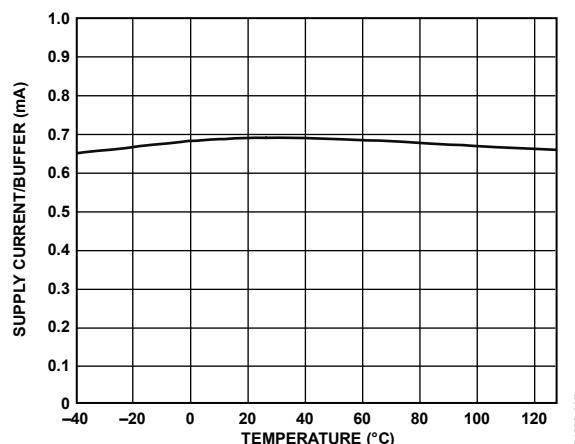
*Figure 3. Input Offset Voltage Distribution*



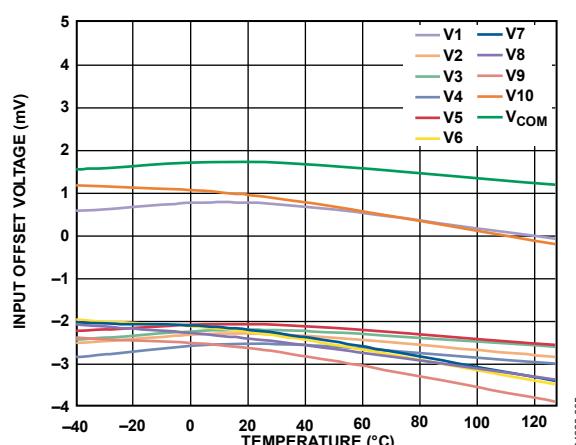
*Figure 6. Supply Current/Buffer vs. Supply Voltage*



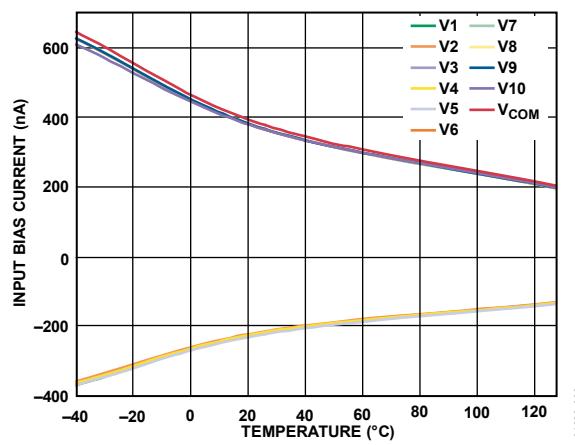
*Figure 4. Input Offset Voltage Drift Distribution*



*Figure 7. Supply Current/Buffer vs. Temperature*

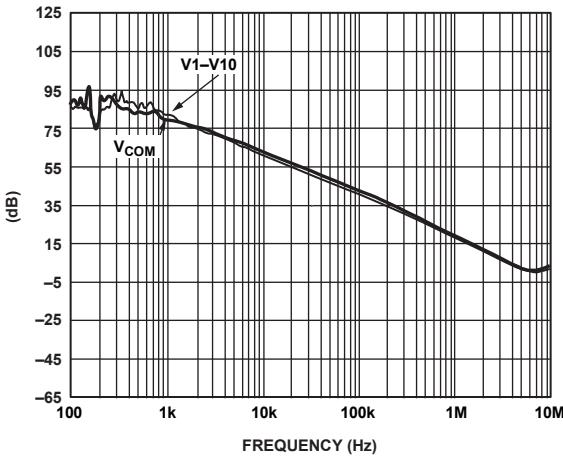


*Figure 5. Input Offset Voltage vs. Temperature*

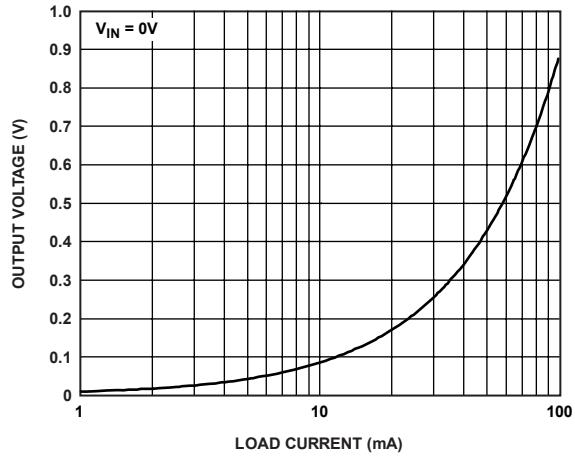


*Figure 8. Input Bias Current vs. Temperature*

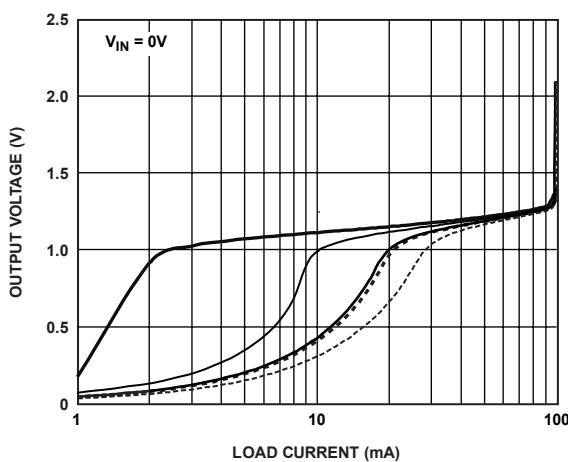
# ADD8710



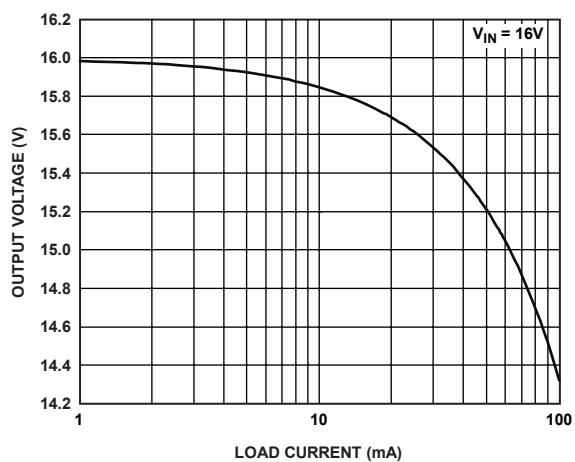
04889-009



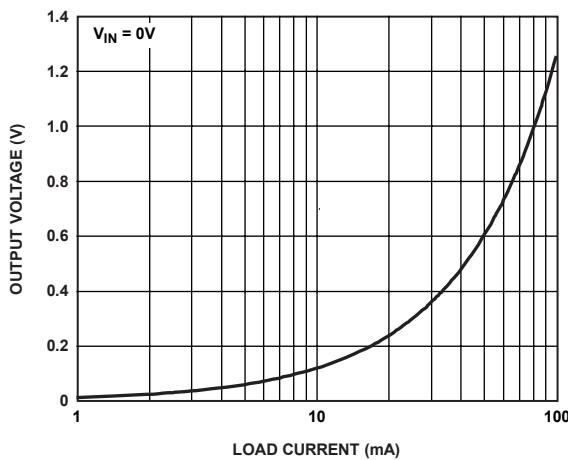
04889-012



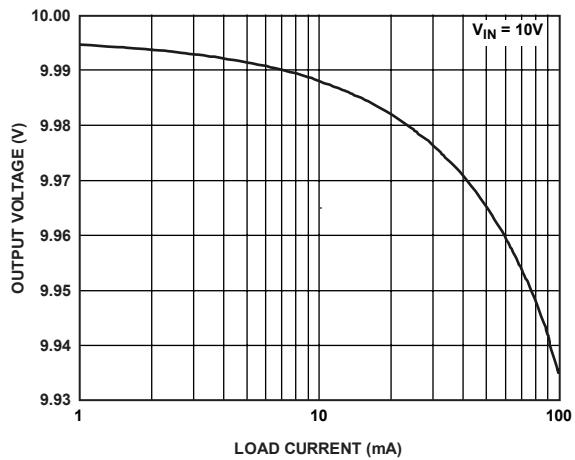
04889-010



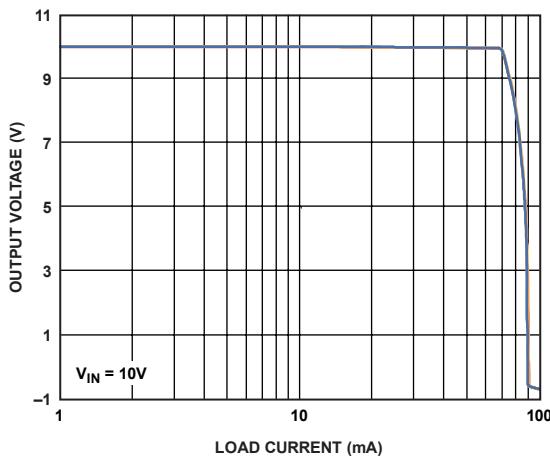
04889-013



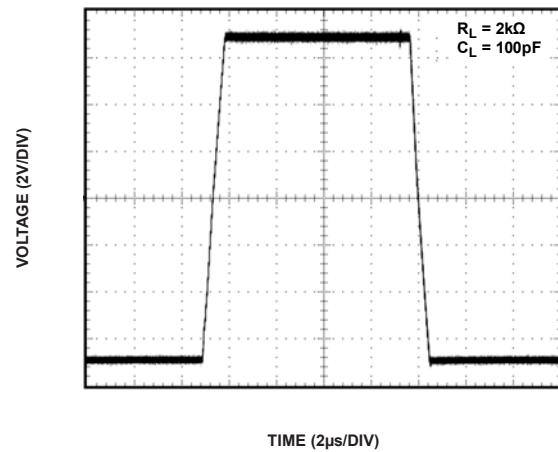
04889-011



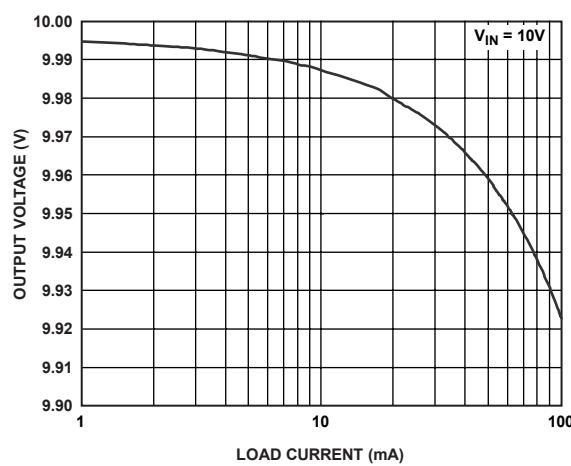
04889-014



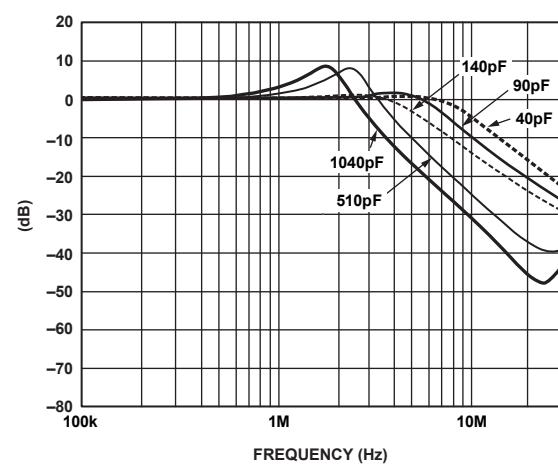
04889-015



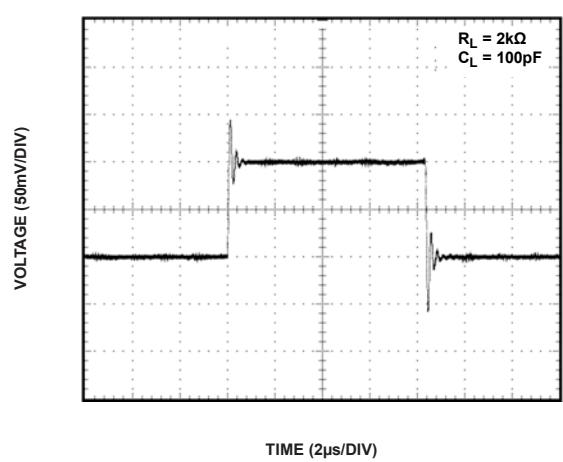
04889-018



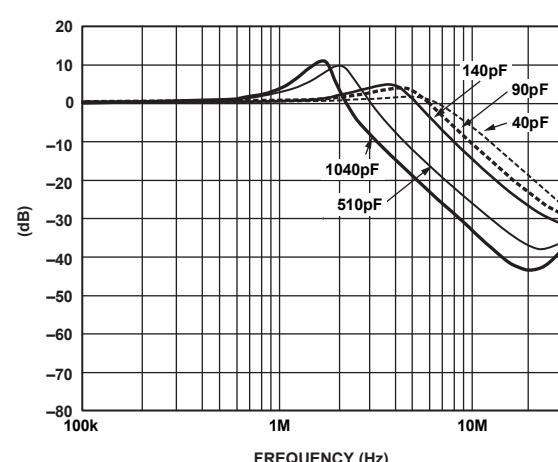
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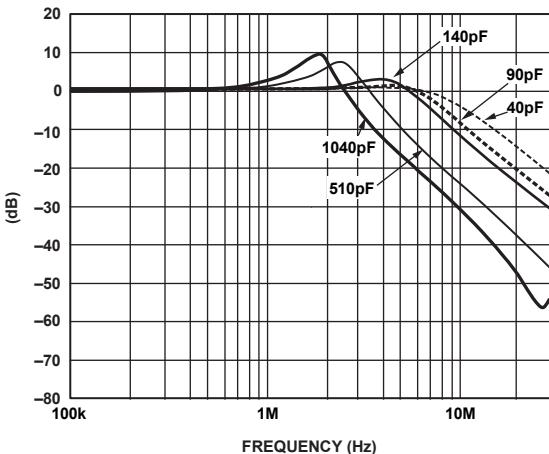


Figure 21. Channel  $V_{COM}$  Frequency Response vs. Capacitive Loading

04889-021

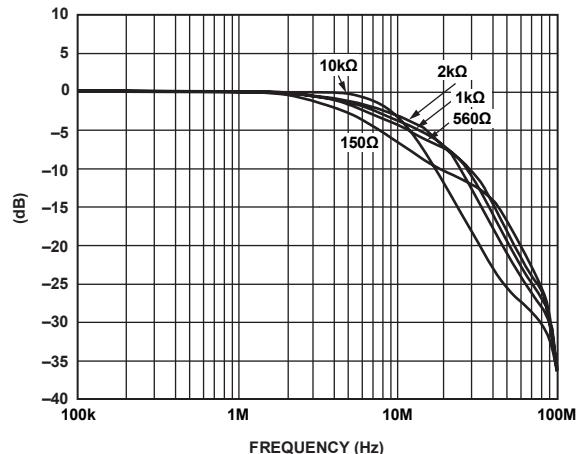


Figure 24. Channel  $V_{COM}$  Frequency Response vs. Resistive Loading

04889-024

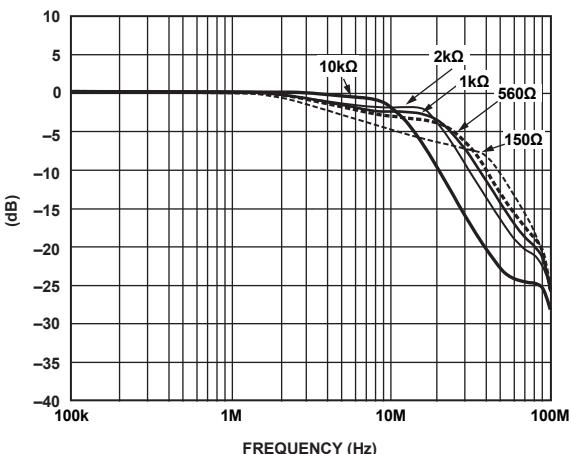


Figure 22. Channel 1 to Channel 5 Frequency Response vs. Resistive Loading

04889-022

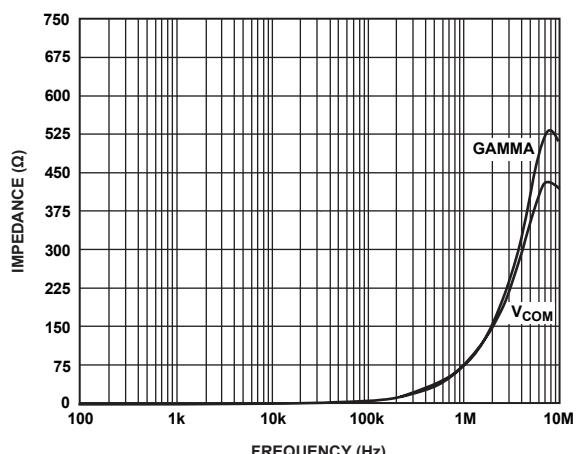


Figure 25. Closed-Loop Output Impedance vs. Frequency

04889-025

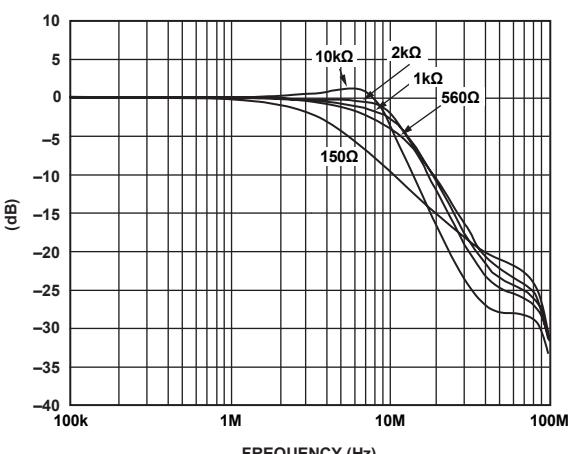


Figure 23. Channel 6 to Channel 10 Frequency Response vs. Resistive Loading

04889-023

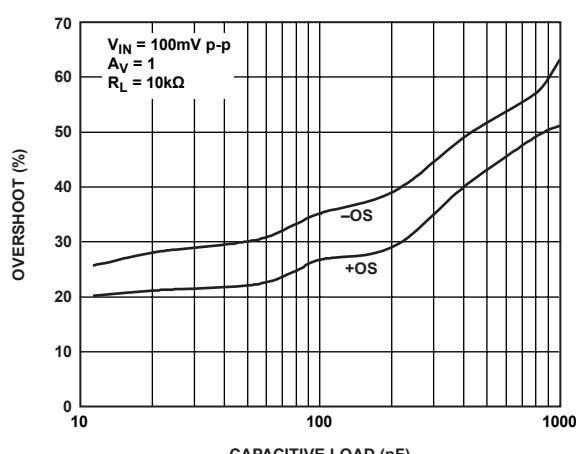


Figure 26. Channel 1 to Channel 5 Small Signal Overshoot vs. Load Capacitance

04889-026

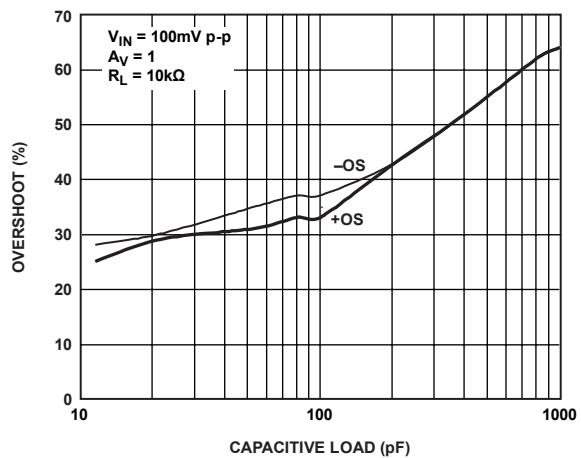
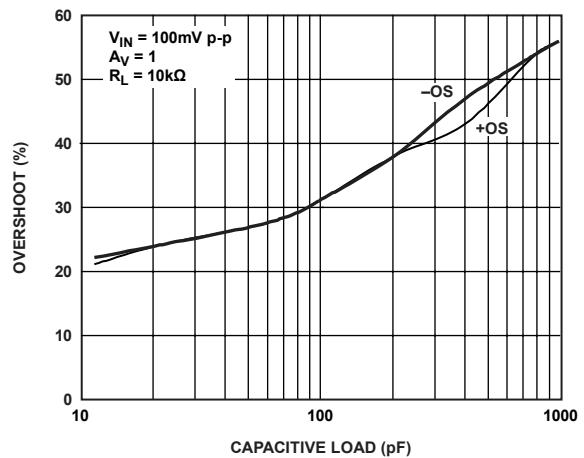


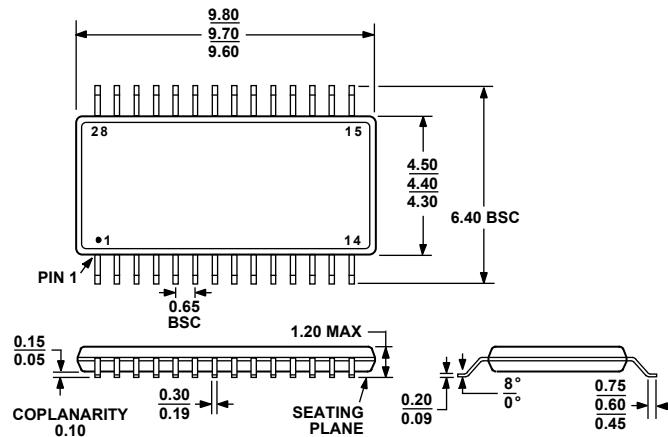
Figure 27. Channel 6 to Channel 10 Small Signal Overshoot vs. Load Capacitance

04889-027

Figure 28. Channel  $V_{COM}$  Small Signal Overshoot vs. Load Capacitance

04889-028

## OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-153-AE

Figure 29. 28-Lead Thin Shrink Small Outline Package [TSSOP]  
(RU-28)

Dimensions shown in millimeters

## ORDERING GUIDE

Model	Temperature Range	Package Description	Package Option
ADD8710ARUZ <sup>1</sup>	-40°C to +85°C	28-Lead TSSOP	RU-28
ADD8710ARUZ-REEL <sup>1</sup>	-40°C to +85°C	28-Lead TSSOP	RU-28

<sup>1</sup> Z = RoHS Compliant Part.

**ADD8710**

**NOTES**

# ADD8710

## NOTES

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